SCDS041H - DECEMBER 1997 - REVISED OCTOBER 2003

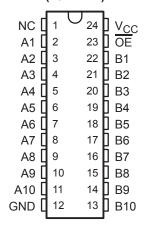
- 5-Ω Switch Connection Between Two Ports
- Rail-to-Rail Switching on Data I/O Ports
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Flow-Through Architecture Optimizes PCB Layout
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

### description/ordering information

The SN74CBTLV3861 provides ten bits of high-speed bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The device is organized as one 10-bit bus switch. When output enable  $(\overline{OE})$  is low, the 10-bit bus switch is on, and port A is connected to port B. When  $\overline{OE}$  is high, the switch is open, and the high-impedance state exists between the two ports.

# DBQ, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



NC - No internal connection

This device is fully specified for partial-power-down applications using I off. The I off feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### ORDERING INFORMATION

TA	PACK	AGET	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP - DBQ	Tape and reel	SN74CBTLV3861DBQR	CBTLV3861
	0010 PW	Tube	SN74CBTLV3861DW	ODTI \ (0004
-40°C to 85°C	SOIC - DW	Tape and reel	SN74CBTLV3861DWR	CBTLV3861
-40 C to 65 C	SOP - NS	Tape and reel	SN74CBTLV3861NSR	CBTLV3861
	TSSOP - PW	Tape and reel	SN74CBTLV3861PWR	CL861
	TVSOP - DGV	Tape and reel	SN74CBTLV3861DGVR	CL861

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

INPUT OE	FUNCTION					
L	A port = B port					
Н	Disconnect					

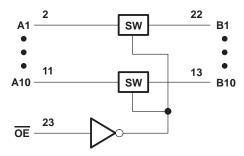


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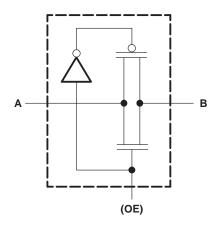


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### logic diagram (positive logic)



## simplified schematic, each FET switch



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub> 0.5 V to	4.6 V
Input voltage range, V <sub>I</sub> (see Note 1)0.5 V to	4.6 V
Continuous channel current	28 mA
Input clamp current, $I_{IK}$ ( $V_{I/O} < 0$ )	50 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2): DBQ package	1°C/W
DGV package 8	6°C/W
DW package 4	6°C/W
NS package 6	5°C/W
PW package 8	8°C/W
Storage temperature range, T <sub>stg</sub> –65°C to	150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.



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### recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
Vcc	Supply voltage		2.3	3.6	V
V	V <sub>CC</sub> = 2.3 V to 2.7 V		1.7		V
V <sub>IH</sub>	High-level control input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		V
V	Law lavel control input valtage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	.,
$V_{IL}$	Low-level control input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		8.0	V
TA	Operating free-air temperature		-40	85	°C

NOTE 3: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER		TEST CONDITI	MIN	TYP†	MAX	UNIT	
VIK		V <sub>CC</sub> = 3 V,	I <sub>I</sub> = −18 mA				-1.2	V
Ц		V <sub>CC</sub> = 3.6 V,	$V_I = V_{CC}$ or GND				±1	μΑ
l <sub>off</sub>		V <sub>CC</sub> = 0,	$V_{I}$ or $V_{O} = 0$ to 3.6 V	1			10	μΑ
ICC		V <sub>CC</sub> = 3.6 V,	I <sub>O</sub> = 0,	$V_I = V_{CC}$ or GND			10	μΑ
∆l <sub>CC</sub> ‡	Control inputs	V <sub>CC</sub> = 3.6 V,	One input at 3 V,	Other inputs at V <sub>CC</sub> or GND			300	μΑ
Ci	Control inputs	V <sub>I</sub> = 3 V or 0				3		pF
C <sub>io(OFI</sub>	F)	$V_{O} = 3 \text{ V or } 0,$	OE = V <sub>CC</sub>			5		pF
		.,		I <sub>I</sub> = 64 mA		5	8	
		$V_{CC} = 2.3 \text{ V},$ TYP at $V_{CC} = 2.5 \text{ V}$	V <sub>I</sub> = 0	I <sub>I</sub> = 24 mA		5	8	
r 8		111 dt vCC 2.0 v	V <sub>I</sub> = 1.7 V,	I <sub>I</sub> = 15 mA		27	40	0
r <sub>on</sub> §			\\\ - 0	I <sub>I</sub> = 64 mA		5	7	Ω
		V <sub>CC</sub> = 3 V	V <sub>I</sub> = 0	I <sub>I</sub> = 24 mA		5	7	
			V <sub>I</sub> = 2.4 V,	I <sub>I</sub> = 15 mA		10	15	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC}$  = 3.3 V (unless otherwise noted),  $T_A$  = 25°C.

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO	V <sub>CC</sub> =		V <sub>CC</sub> =		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
$t_{pd}\P$	A or B	B or A		0.15		0.25	ns
t <sub>en</sub>	ŌE	A or B	2.1	5.5	2.1	4.9	ns
<sup>t</sup> dis	ŌĒ	A or B	1.7	5.5	2.5	5.8	ns

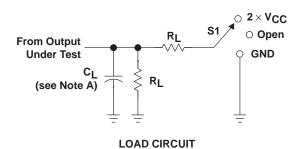
<sup>¶</sup> The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



<sup>†</sup> This is the increase in supply current for each input that is at the specified voltage level, rather than V<sub>CC</sub> or GND.

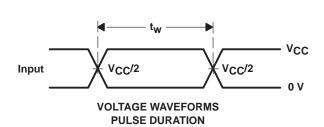
<sup>§</sup> Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

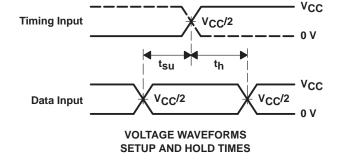
#### PARAMETER MEASUREMENT INFORMATION

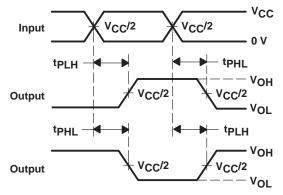


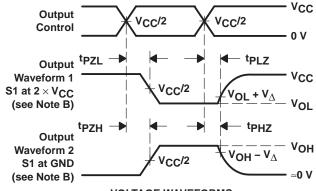
TEST	S1
tPLH/tPHL	Open
tPLZ/tPZL	2×V <sub>CC</sub>
tPHZ/tPZH	GND

VCC	CL	RL	$v_{\scriptscriptstyle\Delta}$
2.5 V ±0.2 V	30 pF	500 Ω	0.15 V
3.3 V ±0.3 V	50 pF	500 Ω	0.3 V









**VOLTAGE WAVEFORMS** PROPAGATION DELAY TIMES **INVERTING AND NONINVERTING OUTPUTS** 

**VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES** LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_f \leq$  2 ns.  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
74CBTLV3861DGVRG4	Active	Production	TVSOP (DGV)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861
74CBTLV3861DGVRG4.B	Active	Production	TVSOP (DGV)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861
SN74CBTLV3861DBQR	Active	Production	SSOP (DBQ)   24	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CBTLV3861
SN74CBTLV3861DBQR.B	Active	Production	SSOP (DBQ)   24	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CBTLV3861
SN74CBTLV3861DGVR	Active	Production	TVSOP (DGV)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861
SN74CBTLV3861DGVR.B	Active	Production	TVSOP (DGV)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861
SN74CBTLV3861DW	Active	Production	SOIC (DW)   24	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV3861
SN74CBTLV3861DW.B	Active	Production	SOIC (DW)   24	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV3861
SN74CBTLV3861DWR	Active	Production	SOIC (DW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV3861
SN74CBTLV3861DWR.B	Active	Production	SOIC (DW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV3861
SN74CBTLV3861NSR	Active	Production	SOP (NS)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV3861
SN74CBTLV3861NSR.B	Active	Production	SOP (NS)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CBTLV3861
SN74CBTLV3861PW	Active	Production	TSSOP (PW)   24	60   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861
SN74CBTLV3861PW.B	Active	Production	TSSOP (PW)   24	60   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861
SN74CBTLV3861PWR	Active	Production	TSSOP (PW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861
SN74CBTLV3861PWR.B	Active	Production	TSSOP (PW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861
SN74CBTLV3861PWRG4	Active	Production	TSSOP (PW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861
SN74CBTLV3861PWRG4.B	Active	Production	TSSOP (PW)   24	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CL861

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

## **PACKAGE OPTION ADDENDUM**

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(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF SN74CBTLV3861:

Automotive: SN74CBTLV3861-Q1

NOTE: Qualified Version Definitions:

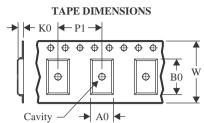
Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74CBTLV3861DGVRG4	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74CBTLV3861DBQR	SSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74CBTLV3861DGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74CBTLV3861DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74CBTLV3861NSR	SOP	NS	24	2000	330.0	24.4	8.3	15.4	2.6	12.0	24.0	Q1
SN74CBTLV3861PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74CBTLV3861PWRG4	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1



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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74CBTLV3861DGVRG4	TVSOP	DGV	24	2000	353.0	353.0	32.0
SN74CBTLV3861DBQR	SSOP	DBQ	24	2500	353.0	353.0	32.0
SN74CBTLV3861DGVR	TVSOP	DGV	24	2000	353.0	353.0	32.0
SN74CBTLV3861DWR	SOIC	DW	24	2000	350.0	350.0	43.0
SN74CBTLV3861NSR	SOP	NS	24	2000	356.0	356.0	45.0
SN74CBTLV3861PWR	TSSOP	PW	24	2000	353.0	353.0	32.0
SN74CBTLV3861PWRG4	TSSOP	PW	24	2000	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74CBTLV3861DW	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74CBTLV3861DW.B	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74CBTLV3861PW	PW	TSSOP	24	60	530	10.2	3600	3.5
SN74CBTLV3861PW.B	PW	TSSOP	24	60	530	10.2	3600	3.5

DBQ (R-PDSO-G24)

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AE.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DW (R-PDSO-G24)

## PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

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- 9. Board assembly site may have different recommendations for stencil design.



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